

20kV, 55mA, Fast Recovery SMD High Voltage Diode

Features

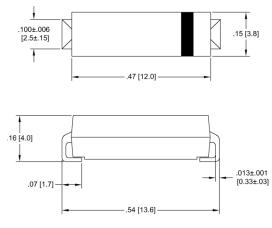
- Surface mount, J-leaded package
- Available in cut tape and 1,000 piece reels
- Molded plastic body, ANSI/UL94 V-0 rated material
- RoHS compliant to Directive 2011/65/EC, Article 4(1), Annex II, Annex III, 7(a) and EU RoHS Directive (EU) 2015/863 of March 2015, Amending Annex II



DEVICE ELECTRICAL CHARACTERISTICS

(25°C ambient temperature unless stated otherwise)	Conditions	Symbol	Value	
Maximum Repetitive Peak Reverse Voltage	-	V_{RRM}	20,000 Volts	
Average Forward Current Maximum	$T_C = 70^{\circ}C$	I _{FAVM}	40 mA	
Average Forward Current Maximum	$T_L = 55^{\circ}C$	I _{FAVM}	55 mA	
Average Forward Current Maximum	$T_L = 100^{\circ}C$	I _{FAVM}	20 mA	
Thermal Resistance (typical) in °C/W	Leads mounted on 5mm x 5mm	RΘ	ROJC	ROJL
	copper pad.		57	50
Maximum Forward Voltage Drop	$I_F = 60 \text{mA}$	V_{F}	40 Volts	
Maximum Surge Current Rating	8.3msec, half sine	I _{FSM}	3 Amps	
Maximum Reverse Current	at rated V _{RRM}	I_R	0.5 μΑ	
Maximum Reverse Recovery Time	IF=20mA; IR=-50mA; Irr=-10mA	TRR	100 ηs	
Junction Capacitance (typical)	f = 1MHz, Vr = 0VDC	C₁	0.6 pf	
Maximum Junction Temperature		TJ	125°C	
Storage Temperature Range	_	T _{STG}	-55°C to 150°C	

MECHANICAL DATA:



DIMENSIONS IN INCHES (MM)

VERSION: 1.0

EFFECTIVE: 17 AUGUST 2017

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